NSN 5961-01-299-8457

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Inclosure Material:

Metal

Overall Length:

1.252 inches

Overall Height:

Between 0.250 inches and 0.340 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact-darlington connected

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Burn in

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage/static/emitter open and 5.0 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

Between 80.00 milliamperes source cutoff current and 4.00 amperes source cutoff current

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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